

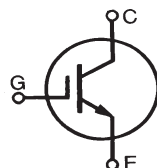
# High Voltage IGBTs

## IXGK100N170 IXGX100N170

$$V_{CES} = 1700V$$

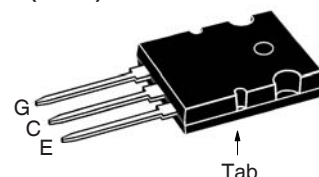
$$I_{C90} = 100A$$

$$V_{CE(sat)} \leq 3.0V$$

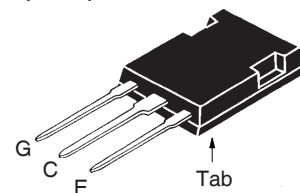


| Symbol                        | Test Conditions  | Maximum Ratings                         |            |
|-------------------------------|--|---|------------|
| $V_{CES}$                     | $T_J = 25^\circ C$ to $150^\circ C$  | 1700                                    | V          |
| $V_{CGR}$                     | $T_J = 25^\circ C$ to $150^\circ C$ , $R_{GE} = 1M\Omega$                                    | 1700                                    | V          |
| $V_{GES}$                     | Continuous   | $\pm 20$                                | V          |
| $V_{GEM}$                     | Transient  | $\pm 30$                                | V          |
| $I_{C25}$                     | $T_C = 25^\circ C$ ( Chip Capability )   | 170                                     | A          |
| $I_{LRMS}$                    | Terminal Current Limit   | 160                                     | A          |
| $I_{C90}$                     | $T_C = 90^\circ C$   | 100                                     | A          |
| $I_{CM}$                      | $T_C = 25^\circ C$ , 1ms   | 600                                     | A          |
| <b>SSOA</b><br><b>(RBSOA)</b> | $V_{GE} = 15V$ , $T_{VJ} = 125^\circ C$ , $R_G = 1\Omega$<br>Clamped Inductive Load          | $I_{CM} = 200$<br>$@ 0.8 \cdot V_{CES}$ | A          |
| $t_{sc}$<br><b>(SCSOA)</b>    | $V_{GE} = 15V$ , $V_{CE} = 1250V$ , $T_J = 125^\circ C$<br>$R_G = 10\Omega$ , Non Repetitive | 10                                      | $\mu s$    |
| $P_C$                         | $T_C = 25^\circ C$   | 830                                     | W          |
| $T_J$                         |  | -55 ... +150                            | $^\circ C$ |
| $T_{JM}$                      |  | 150                                     | $^\circ C$ |
| $T_{stg}$                     |  | -55 ... +150                            | $^\circ C$ |
| $T_L$                         | Maximum Lead Temperature for Soldering   | 300                                     | $^\circ C$ |
| $T_{SOLD}$                    | 1.6 mm (0.062in.) from Case for 10s  | 260                                     | $^\circ C$ |
| $M_d$                         | Mounting Torque (TO-264)   | 1.13/10                                 | Nm/lb.in.  |
| $F_C$                         | Mounting Force (PLUS247)   | 20..120 / 4.5..27                       | N/lb.      |
| <b>Weight</b>                 | TO-264   | 10                                      | g          |
|                               | PLUS247  | 6                                       | g          |

TO-264 (IXGK)



PLUS247 (IXGX)



G = Gate                      E = Emitter  
C = Collector                Tab = Collector

### Features

- Optimized for Low Conduction and Switching Losses
- Short Circuit Capability
- High Current Handling Capability

### Advantages

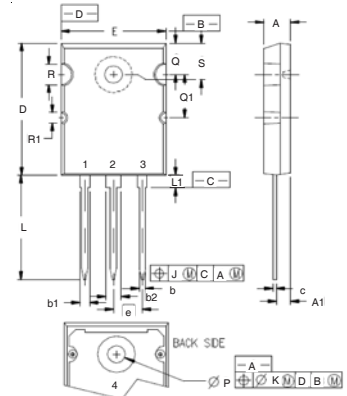
- High Power Density
- Low Gate Drive Requirement

### Applications

- Power Inverters
- UPS
- Motor Drives
- SMPS
- PFC Circuits
- Welding Machines

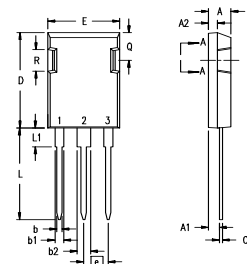
| Symbol        | Test Conditions<br>( $T_J = 25^\circ C$ , Unless Otherwise Specified) | Characteristic Values |      |                    |
|---------------|---|-----------------------|------|--------------------|
|               |   | Min.                  | Typ. | Max.               |
| $BV_{CES}$    | $I_C = 3mA$ , $V_{GE} = 0V$   | 1700                  |      | V                  |
| $V_{GE(th)}$  | $I_C = 8mA$ , $V_{CE} = V_{GE}$                                       | 3.0                   |      | 5.0 V              |
| $I_{CES}$     | $V_{CE} = V_{CES}$ , $V_{GE} = 0V$<br>$T_J = 125^\circ C$             |                       |      | 50 $\mu A$<br>3 mA |
| $I_{GES}$     | $V_{CE} = 0V$ , $V_{GE} = \pm 20V$                                    |                       |      | $\pm 200$ nA       |
| $V_{CE(sat)}$ | $I_C = 100A$ , $V_{GE} = 15V$ , Note 1                                |                       | 2.5  | 3.0 V              |

| Symbol Test Conditions<br>( $T_J = 25^\circ\text{C}$ Unless Otherwise Specified) |   | Characteristic Values  |      |                    |
|--|---|--|------|--------------------|
|  |   | Min.   | Typ. | Max.               |
| $g_{fs}$   | $I_C = 60\text{A}, V_{CE} = 10\text{V}$ , Note 1  | 36   | 64   | S                  |
| $C_{ies}$  | $V_{CE} = 25\text{V}, V_{GE} = 0\text{V}, f = 1\text{MHz}$  |  | 9200 | pF                 |
| $C_{oes}$  |   |  | 455  | pF                 |
| $C_{res}$  |   |  | 150  | pF                 |
| $Q_g$  | $I_C = 100\text{A}, V_{GE} = 15\text{V}, V_{CE} = 0.5 \cdot V_{CES}$  |  | 425  | nC                 |
| $Q_{ge}$   |   |  | 65   | nC                 |
| $Q_{gc}$   |   |  | 186  | nC                 |
| $t_{d(on)}$  | <b>Resistive load, <math>T_J = 25^\circ\text{C}</math></b><br>$I_C = 100\text{A}, V_{GE} = 15\text{V}$<br>$V_{CE} = 0.5 \cdot V_{CES}, R_G = 1\Omega$ |  | 35   | ns                 |
| $t_r$  |   |  | 192  | ns                 |
| $t_{d(off)}$   |   |  | 285  | ns                 |
| $t_f$  |   |  | 395  | ns                 |
| $t_{d(on)}$  |   | <b>Resistive load, <math>T_J = 125^\circ\text{C}</math></b><br>$I_C = 100\text{A}, V_{GE} = 15\text{V}$<br>$V_{CE} = 0.5 \cdot V_{CES}, R_G = 1\Omega$ |      | 35                 |
| $t_r$  |   |  | 250  | ns                 |
| $t_{d(off)}$   |   |  | 285  | ns                 |
| $t_f$  |   |  | 435  | ns                 |
| $R_{thJC}$   |   |  |      | 0.15               |
| $R_{thCS}$   |   |  |      | $^\circ\text{C/W}$ |

**TO-264 Outline**

 Terminals: 1 = Gate  
 2,4 = Collector  
 3 = Emitter

| SYM              | INCHES   |       | MILLIMETERS |       |
|------------------|----------|-------|-------------|-------|
|                  | MIN      | MAX   | MIN         | MAX   |
| A                | .185     | .209  | 4.70        | 5.31  |
| A1               | .102     | .118  | 2.59        | 3.00  |
| b                | .037     | .055  | 0.94        | 1.40  |
| b1               | .087     | .102  | 2.21        | 2.59  |
| b2               | .110     | .126  | 2.79        | 3.20  |
| c                | .017     | .029  | 0.43        | 0.74  |
| D                | 1.007    | 1.047 | 25.58       | 26.59 |
| E                | .760     | .799  | 19.30       | 20.29 |
| e                | .215 BSC |       | 5.46 BSC    |       |
| J                | .000     | .010  | 0.00        | 0.25  |
| K                | .000     | .010  | 0.00        | 0.25  |
| L                | .779     | .842  | 19.79       | 21.39 |
| L1               | .087     | .102  | 2.21        | 2.59  |
| $\varnothing P$  | .122     | .138  | 3.10        | 3.51  |
| Q                | .240     | .256  | 6.10        | 6.50  |
| Q1               | .330     | .346  | 8.38        | 8.79  |
| $\varnothing R$  | .155     | .187  | 3.94        | 4.75  |
| $\varnothing R1$ | .085     | .093  | 2.16        | 2.36  |
| S                | .243     | .253  | 6.17        | 6.43  |

 Note: 1. Pulse test,  $t \leq 300\mu\text{s}$ , duty cycle,  $d \leq 2\%$ .

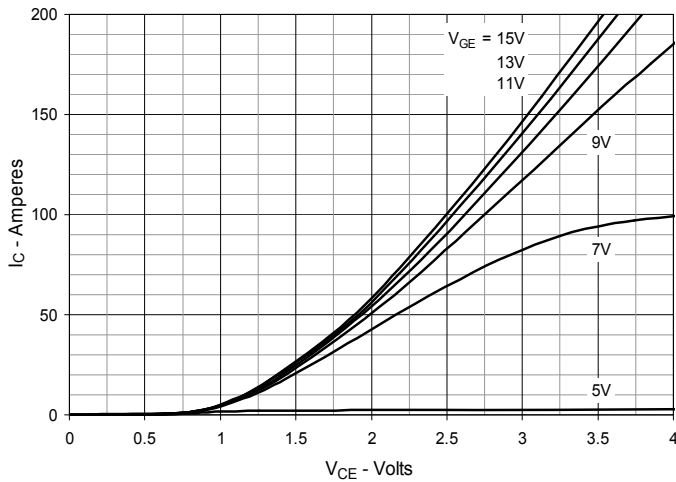
**PLUS247™ Outline**

 Terminals: 1 - Gate  
 2 - Collector  
 3 - Emitter

| Dim.           | Millimeter |       | Inches   |       |
|----------------|------------|-------|----------|-------|
|                | Min.       | Max.  | Min.     | Max.  |
| A              | 4.83       | 5.21  | .190     | .205  |
| A <sub>1</sub> | 2.29       | 2.54  | .090     | .100  |
| A <sub>2</sub> | 1.91       | 2.16  | .075     | .085  |
| b              | 1.14       | 1.40  | .045     | .055  |
| b <sub>1</sub> | 1.91       | 2.13  | .075     | .084  |
| b <sub>2</sub> | 2.92       | 3.12  | .115     | .123  |
| C              | 0.61       | 0.80  | .024     | .031  |
| D              | 20.80      | 21.34 | .819     | .840  |
| E              | 15.75      | 16.13 | .620     | .635  |
| e              | 5.45 BSC   |       | .215 BSC |       |
| L              | 19.81      | 20.32 | .780     | .800  |
| L1             | 3.81       | 4.32  | .150     | .170  |
| Q              | 5.59       | 6.20  | .220     | 0.244 |
| R              | 4.32       | 4.83  | .170     | .190  |

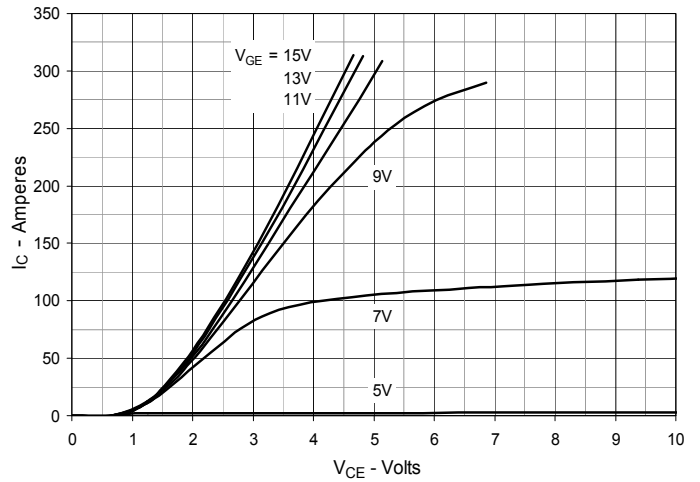
IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

|  |           |           |           |           |              |              |              |              |              |             |
|--|-----------|-----------|-----------|-----------|--------------|--------------|--------------|--------------|--------------|-------------|
| IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: | 4,835,592 | 4,931,844 | 5,049,961 | 5,237,481 | 6,162,665    | 6,404,065 B1 | 6,683,344    | 6,727,585    | 7,005,734 B2 | 7,157,338B2 |
|  | 4,850,072 | 5,017,508 | 5,063,307 | 5,381,025 | 6,259,123 B1 | 6,534,343    | 6,710,405 B2 | 6,759,692    | 7,063,975 B2 |             |
|  | 4,881,106 | 5,034,796 | 5,187,117 | 5,486,715 | 6,306,728 B1 | 6,583,505    | 6,710,463    | 6,771,478 B2 | 7,071,537    |             |

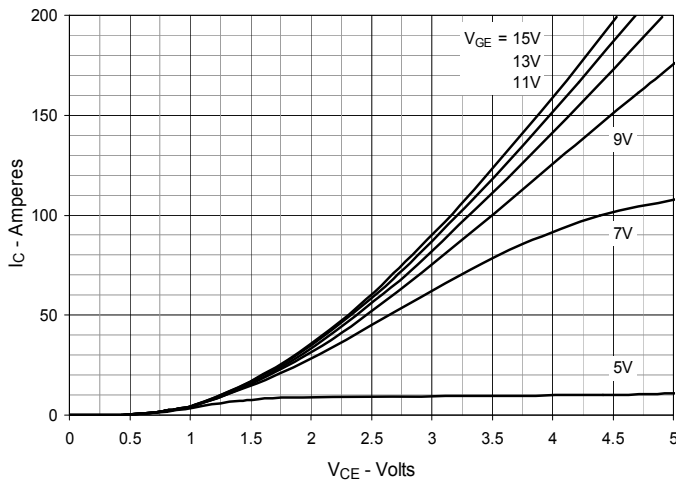
**Fig. 1. Output Characteristics @  $T_J = 25^\circ\text{C}$**



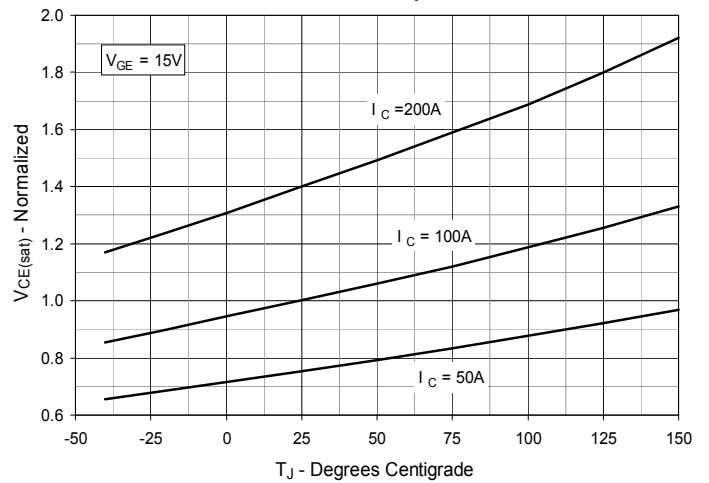
**Fig. 2. Extended Output Characteristics @  $T_J = 25^\circ\text{C}$**



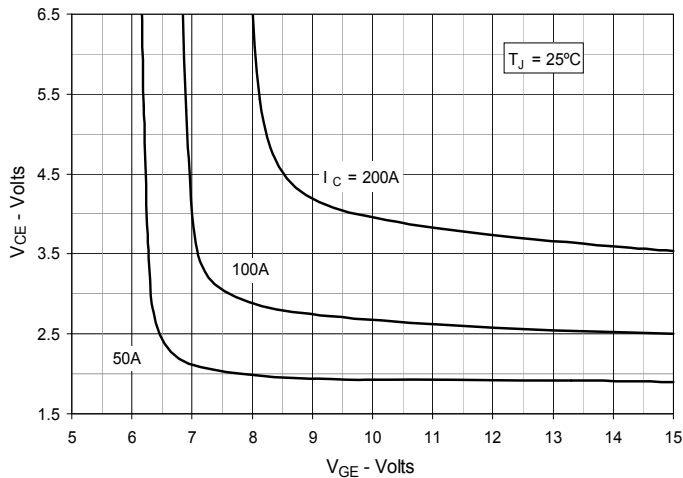
**Fig. 3. Output Characteristics @  $T_J = 125^\circ\text{C}$**



**Fig. 4. Dependence of  $V_{CE(sat)}$  on Junction Temperature**



**Fig. 5. Collector-to-Emitter Voltage vs. Gate-to-Emitter Voltage**



**Fig. 6. Input Admittance**

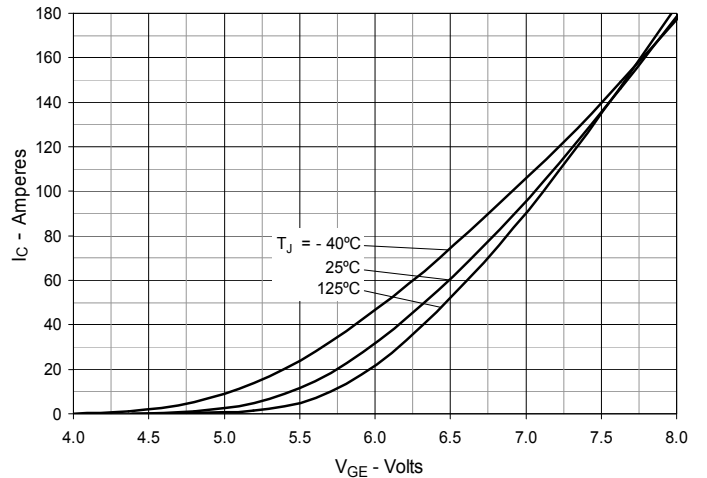


Fig. 7. Transconductance

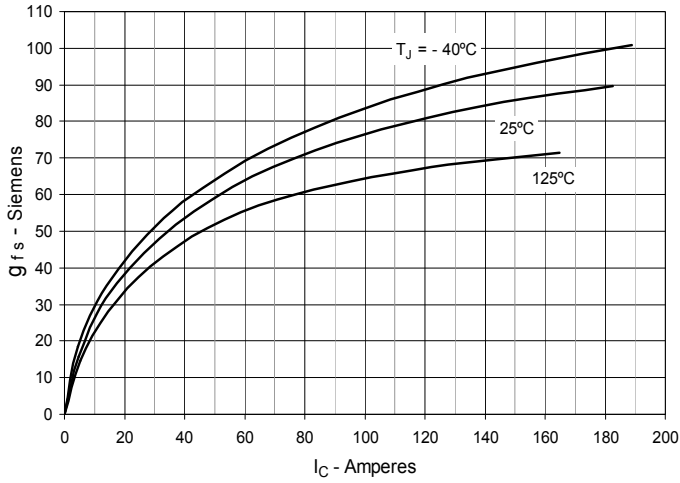


Fig. 8. Gate Charge

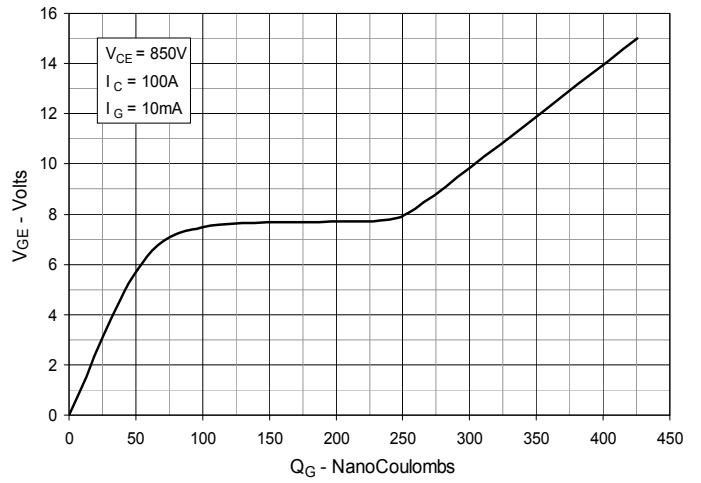


Fig. 9. Reverse-Bias Safe Operating Area

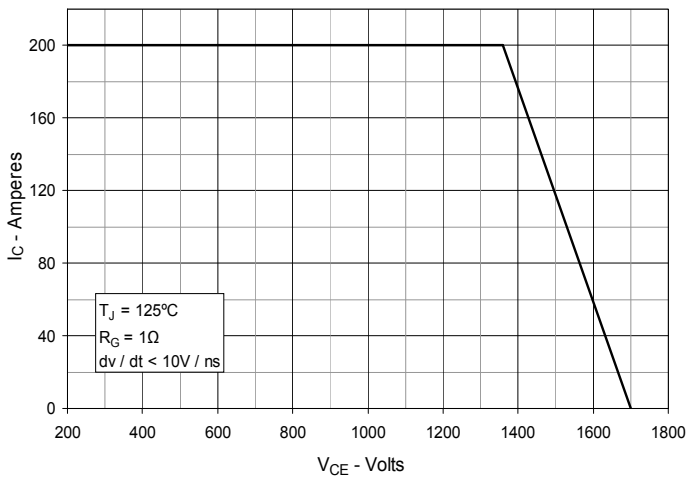


Fig. 10. Capacitance

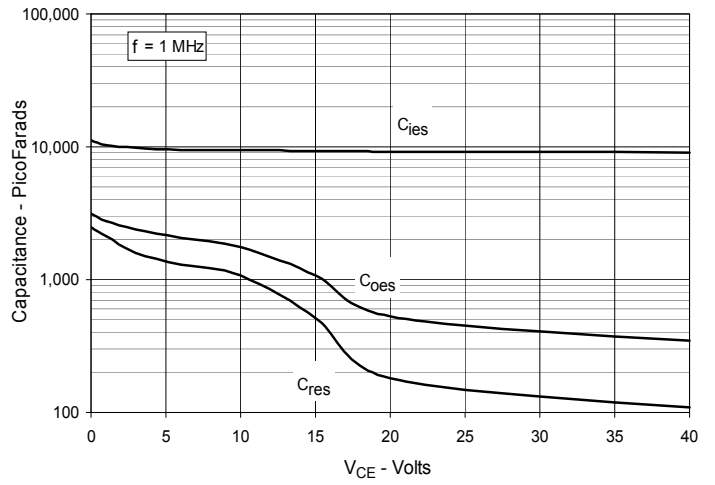
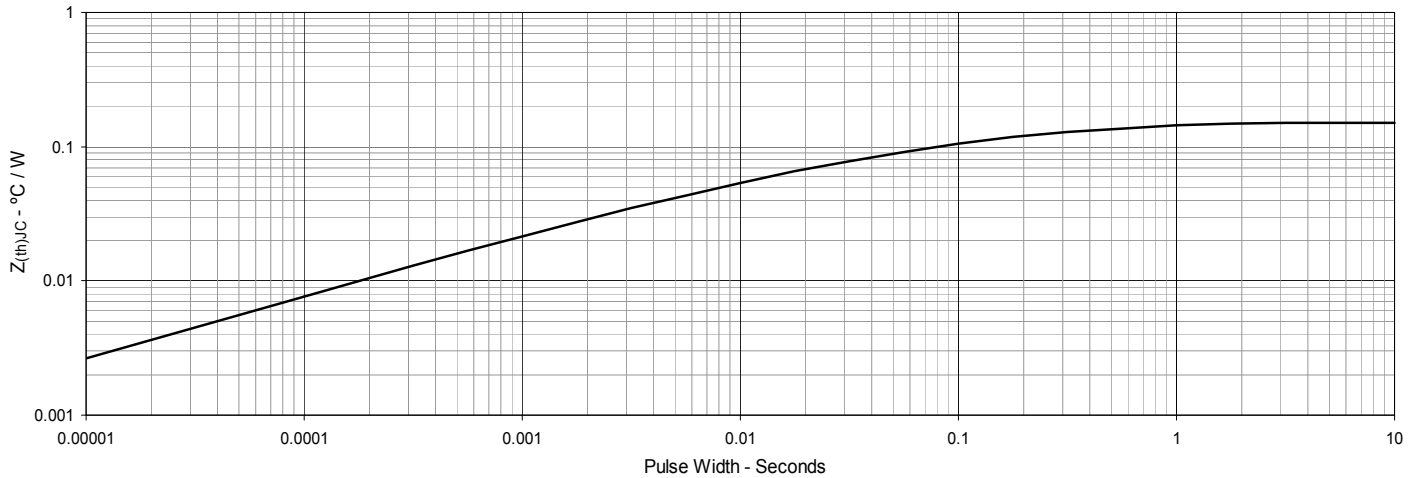
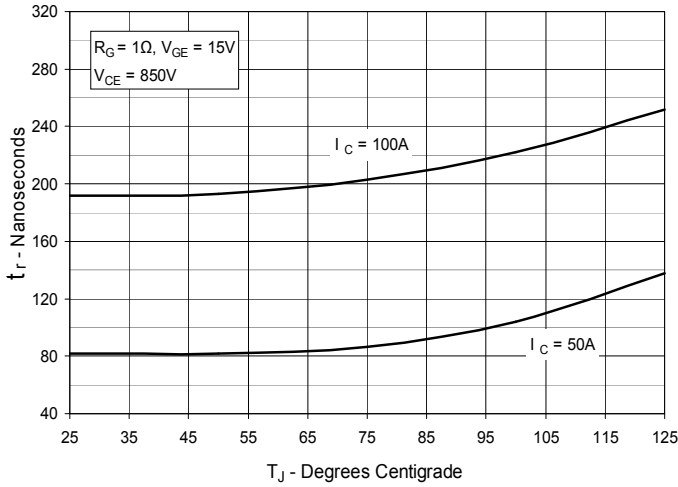


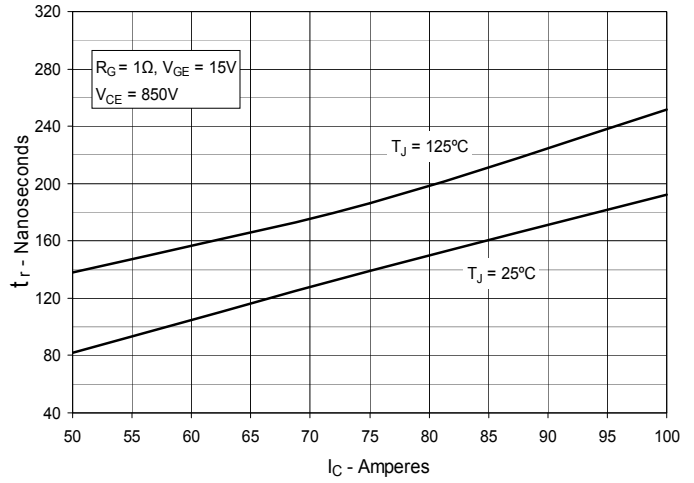
Fig. 11. Maximum Transient Thermal Impedance



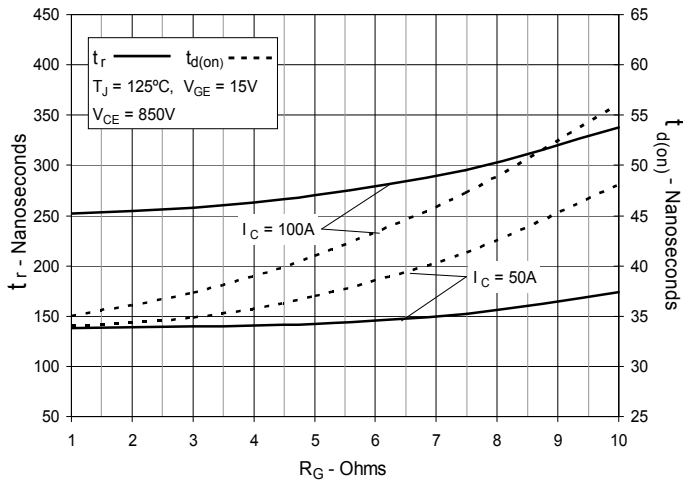
**Fig. 12. Resistive Turn-on Rise Time vs. Junction Temperature**



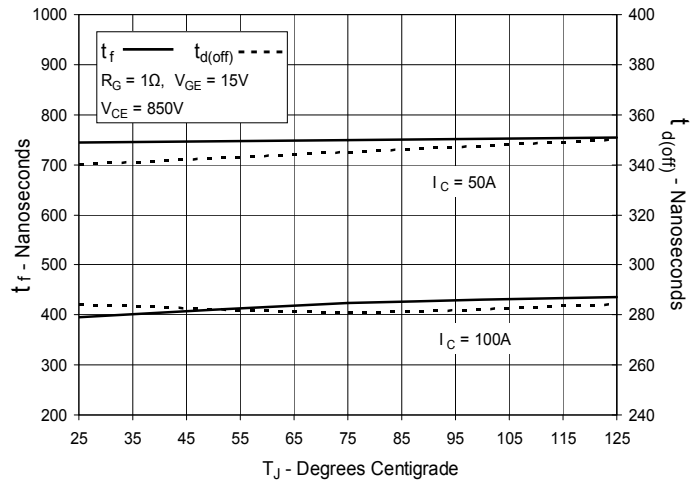
**Fig. 13. Resistive Turn-on Rise Time vs. Collector Current**



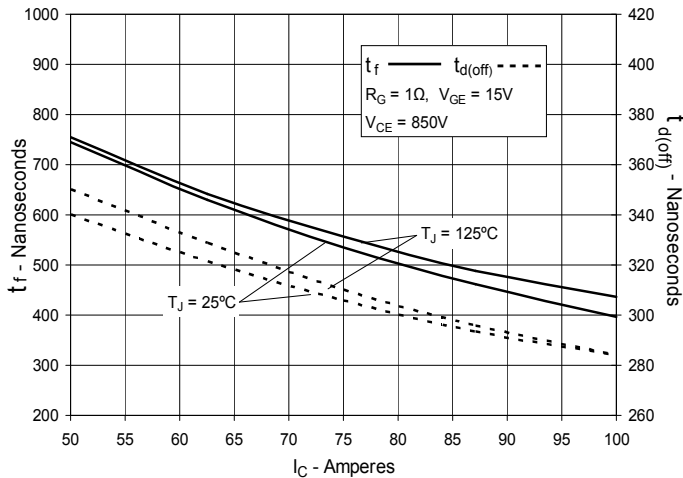
**Fig. 14. Resistive Turn-on Switching Times vs. Gate Resistance**



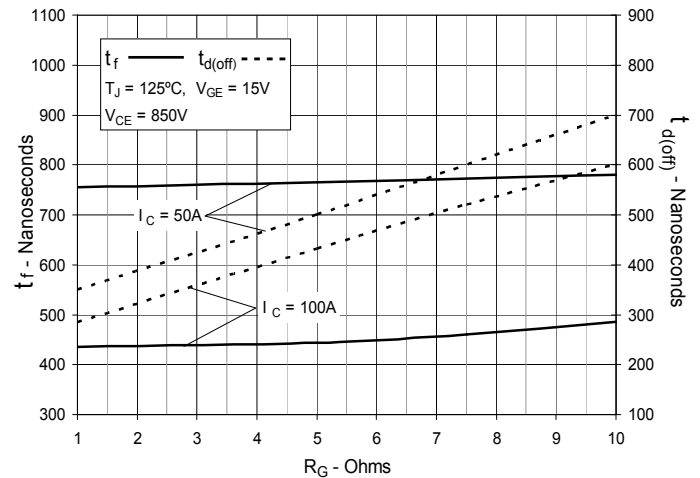
**Fig. 15. Resistive Turn-off Switching Times vs. Junction Temperature**



**Fig. 16. Resistive Turn-off Switching Times vs. Collector Current**



**Fig. 17. Resistive Turn-off Switching Times vs. Gate Resistance**





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